

**IN THE CLAIMS:**

Please amend the claims to read as follows:

1. (Currently Amended): A liquid crystal display device, comprising:  
a plurality of gate lines and data lines crossing each other to define a plurality of pixel regions;  
a plurality of thin film transistors, each disposed in one of the pixel regions, ~~the~~ each thin film transistor including:  
a gate electrode on a first substrate,  
a gate insulating layer over the first substrate,  
a semiconductor layer on the gate insulating layer, and  
source/drain electrodes on the semiconductor layer~~[[,]] and;~~  
a passivation layer over the first substrate including the source/drain electrodes of the thin film transistors; and  
a plurality of pixel electrodes, each disposed in one of the pixel regions; and  
at least one Ti layer on at least one layer of the gate electrode ~~, the semiconductor layer,~~  
and the source/drain electrodes of the thin film ~~transistor~~ transistors.

2. (Canceled).

3. (Currently Amended): The device according to claim [[2]] 1, further comprising a TiO<sub>2</sub> layer formed on at least the passivation layer.

4. (Original): The device according to claim 3, wherein a surface of the TiO<sub>2</sub> layer has hydrophilic properties.

5. (Canceled).

6. (Previously Presented): The device according to claim 1, wherein the Ti layer is formed on the semiconductor layer to function as an ohmic contact layer.

7. (Original): The device according to claim 1, further comprising:  
a black matrix on a second substrate;  
a color filter layer on the second substrate; and  
a liquid crystal material layer between the first and second substrates.

8. (Original): The device according to claim 1, further comprising a TiO<sub>2</sub> layer formed on at least each of the pixel electrodes.

9. (Original): The device according to claim 8, wherein a surface of the TiO<sub>2</sub> layer has hydrophilic properties.

10. (Original): The device according to claim 1, further comprising at least one TiO<sub>2</sub> layer formed in the thin film transistors.

11. (Original): The device according to claim 10, wherein a surface of the TiO<sub>2</sub> layer has hydrophilic properties.

12. (Original): A liquid crystal display device, comprising:  
a plurality of gate lines and data lines crossing each other to define a plurality of pixel regions;  
a thin film transistor in each pixel region;  
a pixel electrode in each pixel region; and  
a metal masking layer in the thin film transistor.

13. (Original): The device according to claim 12, wherein the metal masking layer includes Ti.

14. (Original): The device according to claim 12, wherein the metal masking layer

including a Ti layer, and a TiO<sub>2</sub> layer having a hydrophilic surface.

Claims 15-70 (Canceled).

71. (Previously Presented): The device according to claim 12, wherein the metal masking layer includes Ti and is disposed on upper surfaces of each of a gate electrode, a semiconductor layer and source/drain electrodes of the thin film transistor.